

# 1.7V-6V Vin, 500mA, 8uA Iq, Low-Dropout Regulator

### **FEATURES**

- Wide Input Range: 1.7V-6V (2.2V-6V for SCT71005A01)
- Maximum Output Current: 500mA
- Output Voltage:
  - > 1.2V, 1.8V and 3.3V (Fixed Output)
  - 0.7V~5V (Adjustable Output Version-SCT71005A01)
  - 0.5V~5V (Adjustable Output Version-SCT71005A02)
- Output Voltage Accuracy:
  - > T<sub>J</sub>= 25°C : ±1%
  - > T<sub>J</sub>= -40 °C~ 125 °C : ±2%
- Low Quiescent Current: 8uA
- Ultra-Low Shutdown Current: 0.02uA
- Low Dropout Voltage(Adjustable Output Version):
  - > 54mV at 200mA load current
  - > 143mV at 500mA load current
- Support Output Capacitors Range:
  - ≥ 2.2uF~220uF
  - Low-ESR: 0.001Ω~ 5 Ω
- 1.4ms Internal Soft-start Time(V<sub>REF</sub>=500mV)
- 2.05ms Internal Soft-start Time(V<sub>REF</sub>=700mV)
- Integrated Short-Circuit Protection with OCFB (Over Current Fold-back) Feature
- Enable pin is available
- Over-Temperature Protection
- Power-Good Feature is available
- Active Output Discharge
- Available Package: SOT23-5/ TDFN2x2-6/ TDFN2x3-8/ DFN1x1-4

### APPLICATIONS

- Battery-Powered Systems
- Automotive infotainment
- Navigation systems
- Portable appliances

### **DESCRIPTION**

The SCT71005 series products is a low-dropout linear regulator designed to operate with a wide input-voltage range from 1.7 V to 6 V and 500mA output current with enable control and Power-Good feature. The SCT71005 series products is stable with 2.2uF~220uF output capacitors, and 10uF ceramic capacitor is recommended.

Only 8-µA typical quiescent current at light load makes the SCT71005 series products ideal choices for portable devices with battery power supply and an optimal solution for powering microcontrollers (MCUs) and CAN/LIN transceivers in always-on systems.

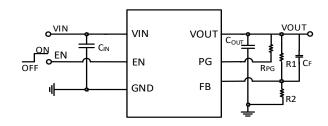
The SCT71005 series products implements power good circuit (PG) which indicates that output voltage is in regulation. This signal could be used for power sequencing or as a microcontroller reset.

The SCT71005 series products integrated short-circuit and overcurrent protection with OCFB (Over Current Fold-back) feature, which makes the device more reliable during transient high-load current faults or shorting events.

The SCT71005 series products provide fixed 1.2V,1.8V and 3.3V output voltage versions, and also could provide adjust output voltage version with 0.7V、0.5V feedback voltage.

The SCT71005 series products is available in SOT23-5, TDFN2x2-6, DFN1x1-4 and TDFN2x3-8 packages, for other package options, please contact SCT sales.

### TYPICAL APPLICATION





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Product Folder Links: SCT71005 Series

### **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Revision 1.0: Release to production.

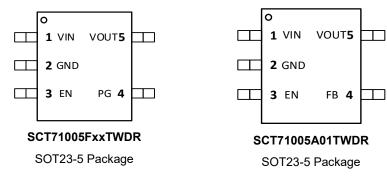
Revision 1.1: Update Figure 8, the electrical characteristics and the thermal performance on page 20.

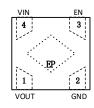
# **DEVICE ORDER INFORMATION**

Orderable Device	Output Voltage	Package	Package Marking	PINS	Transport Media, Quantity	
SCT71005F33TWDR	Fixed 3.3V	SOT23-5	5F33	5	Tape & Reel, 3000	
SCT71005F18TWDR	Fixed 1.8V	SOT23-5	5F18	5	Tape & Reel, 3000	
SCT71005F12TWDR	Fixed 1.2V	SOT23-5	5F12	5	Tape & Reel, 3000	
SCT71005A01TWDR	Adjust	SOT23-5	5A01	5	Tape & Reel, 3000	
SCT71005F33DVAR	Fixed 3.3V	TDFN2X2-6	5F33	6	Tape & Reel, 3000	
SCT71005F18DVAR	Fixed 1.8V	TDFN2X2-6	5F18	6	Tape & Reel, 3000	
SCT71005F12DVAR	Fixed 1.2V	TDFN2X2-6	5F12	6	Tape & Reel, 3000	
SCT71005A02DTDR	Adjust	TDFN2X3-8	5A02	8	Tape & Reel, 5000	
SCT71005F33DXAR	Fixed 3.3V	DFN1X1-4	F33	4	Tape & Reel, 10000	
SCT71005F18DXAR	Fixed 1.8V	DFN1X1-4	F18	4	Tape & Reel, 10000	
SCT71005F12DXAR	Fixed 1.2V	DFN1X1-4	F12	4	Tape & Reel, 10000	

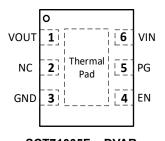


# **PIN CONFIGURATION**

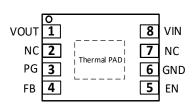




SCT71005FxxDXAR
DFN1x1-4 Package



SCT71005FxxDVAR TDFN2x2-6 Package



SCT71005A02DTDR

TDFN2x3-8 Package

# **PIN FUNCTIONS**

# **SOT23-5/SCT71005Fxx:**

NAME	NAME	PIN FUNCTION	
1	VIN	Input voltage pin	
2	GND	Ground reference pin.	
3	EN	Enable input pin. This pin has an internal resistor( $R_{EN\_pulldown}$ ) to hold the regulator off by default. A low voltage( $V_{EN} < V_{EN\_L}$ ) on this pin turns the regulator off and discharges the output pin to GND through an internal pulldown resistor( $R_{discharge}$ ).A high voltage( $V_{EN} > V_{EN\_H}$ ) on this pin enables the regulator output.The pulldown resistor( $R_{EN\_pulldown}$ ). $R_{EN\_pulldown}$ Is disconnected to reduce input current when $V_{EN} > V_{EN\_H}$ .	
4	PG	Power-good pin	
5	VOUT	Regulated output voltage pin	



# SOT23-5/SCT71005A01:

NAME	NAME	PIN FUNCTION
1	VIN	Input voltage pin
2	GND	Ground reference pin.
3	EN	Enable input pin. This pin has an internal resistor( $R_{EN\_pulldown}$ ) to hold the regulator off by default. A low voltage( $V_{EN} < V_{EN\_L}$ ) on this pin turns the regulator off and discharges the output pin to GND through an internal pulldown resistor( $R_{discharge}$ ). A high voltage( $V_{EN} > V_{EN\_H}$ ) on this pin enables the regulator output. The pulldown resistor( $R_{EN\_pulldown}$ ). $R_{EN\_pulldown}$ Is disconnected to reduce input current when $V_{EN} > V_{EN\_H}$ .
4	FB	Feedback voltage pin
5	VOUT	Regulated output voltage pin

# **TDFN2x2-6/SCT71005Fxx:**

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NAME	NAME	PIN FUNCTION			
1	VOUT	Regulated output voltage pin			
2	NC	No connection			
3	GND	Ground reference pin.			
4	EN	Enable input pin. This pin has an internal resistor( $R_{EN\_pulldown}$ ) to hold the regulator off by default. A low voltage( $V_{EN} < V_{EN\_L}$ ) on this pin turns the regulator off and discharges the output pin to GND through an internal pulldown resistor( $R_{discharge}$ ). A high voltage( $V_{EN} > V_{EN\_H}$ ) on this pin enables the regulator output. The pulldown resistor( $R_{EN\_pulldown}$ ). $R_{EN\_pulldown}$ Is disconnected to reduce input current when $V_{EN} > V_{EN\_H}$ .			
5	PG	Power-good pin			
6	VIN	Input voltage pin			
7	Thermal Pad	Connect the thermal pad to a large area GND plane for improved thermal performance.			



# TDFN2x3-8/SCT71005A02:

NAME	NAME	PIN FUNCTION
1	VOUT	Regulated output voltage pin
2	NC	No connection
3	PG	Power-good pin
4	FB	Feedback voltage pin
5	EN	Enable input pin. This pin has an internal resistor( $R_{EN\_pulldown}$ ) to hold the regulator off by default. A low voltage( $V_{EN} < V_{EN\_L}$ ) on this pin turns the regulator off and discharges the output pin to GND through an internal pulldown resistor( $R_{discharge}$ ). A high voltage( $V_{EN} > V_{EN\_H}$ ) on this pin enables the regulator output. The pulldown resistor( $R_{EN\_pulldown}$ ). $R_{EN\_pulldown}$ Is disconnected to reduce input current when $V_{EN} > V_{EN\_H}$ .
6	GND	Ground reference pin.
7	NC	No connection
8	VIN	Input voltage pin
9	Thermal Pad	Connect the thermal pad to a large area GND plane for improved thermal performance.

### **DFN1X1-4/SCT71005Fxx:**

NAME	NAME	PIN FUNCTION
1	VOUT	Regulated output voltage pin
2	GND	Ground reference pin.
3	EN	Enable input pin. This pin has an internal resistor( $R_{\text{EN\_pulldown}}$ ) to hold the regulator off by default. A low voltage( $V_{\text{EN}} < V_{\text{EN\_L}}$ ) on this pin turns the regulator off and discharges the output pin to GND through an internal pulldown resistor( $R_{\text{discharge}}$ ).A high voltage( $V_{\text{EN}} > V_{\text{EN\_H}}$ ) on this pin enables the regulator output.The pulldown resistor( $R_{\text{EN\_pulldown}}$ ). $R_{\text{EN\_pulldown}}$ Is disconnected to reduce input current when $V_{\text{EN}} > V_{\text{EN\_H}}$ .
4	VIN	Input voltage pin
5	Thermal Pad	Connect the thermal pad to a large area GND plane for improved thermal performance.



### RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range unless otherwise noted

PARAMETER	DEFINITION	MIN	MAX	UNIT
V	Input voltage range	1.7	6	V
Vin	Input voltage range-SCT71005A01	2.2	6	V
	Fixed Output voltage	1.2	3.3	V
Vout	Adjustable Output Version-SCT71005A01	0.7	5	V
	Adjustable Output Version-SCT71005A02	0.5	5	V
V <sub>EN</sub>	Enable input voltage	0	Vin	V
V <sub>PG</sub>	Power-good pin voltage	0	5.5	V
C <sub>IN</sub>	Input capacitor	2.2		uF
Соит	Output capacitor	2.2	220	uF
ESR	Output capacitor ESR requirements	0.001	5	Ω
TJ	Operating junction temperature	-40	125	°C

### ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature range unless otherwise noted (1)

PARAMETER	DEFINITION	MIN	MAX	UNIT
V <sub>IN</sub>	Maximum input voltage range	-0.3	6.5	V
Vout	Maximum output voltage range	-0.3	6	V
V <sub>EN</sub>	Maximum enable input voltage	-0.3	V <sub>IN</sub>	V
V <sub>PG</sub>	Maximum power-good pin voltage	-0.3	6	V
T <sub>J</sub> <sup>(2)</sup>	Junction temperature range	-40	150	°C
T <sub>stg</sub>	Storage temperature range	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Rating may cause device permanent damage. The device is not guaranteed to function outside of its Recommended Operation Conditions.

## **ESD RATINGS**

PARAMETER	DEFINITION  Human Body Model(HBM), per ANSI-JEDEC-JS-001-2014		MAX	UNIT
\/	Human Body Model(HBM), per ANSI-JEDEC-JS-001-2014 specification, all pins <sup>(1)</sup>	-5	+5	kV
Vesd	Charged Device Model(CDM), per ANSI-JEDEC-JS-002-2014 specification, all pins <sup>(2)</sup>	-1	+1	kV

<sup>(1)</sup> JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.



<sup>(2)</sup> The IC includes over temperature protection to protect the device during overload conditions. Junction temperature will exceed 150°C when over temperature protection is active. Continuous operation above the specified maximum operating junction temperature will reduce lifetime.

<sup>(2)</sup> JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### THERMAL INFORMATION

The value of  $R_{\theta JA}$  and  $R_{\theta JC}$  given in this table is only valid for comparison with other packages and cannot be used for design purposes. Because they were simulated in accordance with JESD 51-7. They do not represent the performance obtained in an actual application. For design information see Power Dissipation and Thermal Performance section.

The value of  $R_{\theta JA\_EVM}$  is the tested results based on our EVM, and is more useful for thermal design. Even if it still do not represent the thermal performance of customer's PCB design, but it was a good starting point for thermal performance design.

The PCB information of our EVM: 4-layer,1oz Cu (inner 0.5oz Cu), 50mm x 30mm size.2-layer(only for DFN1X1-4), 1oz Cu, 50mm x 30mm size.

The values given in this table are not a characteristic of package itself, but of many other system level characteristics such as the design and layout of the printed circuit board (PCB), thermal pad size, and external environmental factors. The PCB board is a heat sink that is soldered to the leads and thermal pad of the device. Changing the design or configuration of the PCB board changes the efficiency of the heat sink and therefore the actual values of the below table.

Package Type	R <sub>0JA</sub> <sup>(1)</sup>	Ψ <sub>JT</sub>	Ψ <sub>ЈВ</sub>	R <sub>eJCtop</sub> (2)	R <sub>0JA_EVM</sub> (3)	UNIT
SOT23-5	123.23	34.41	78	129	91.81	
TDFN2X2-6	101.7	25.23	65	166.05	71.31	°C/W
TDFN2X3-8	99.76	24.76	64.7	126.7	59.04	C/VV
DFN1X1-4 (2-layer)	359.64	36.17	96.76	519.17	140.55	

<sup>(1)</sup>  $R_{\text{BJA}}$  is junction to ambient thermal resistance, based on JESD51-7.



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<sup>(2)</sup>  $R_{\theta JC}$  is junction to case thermal resistance, based on JESD51-7.

<sup>(3)</sup>  $R_{\theta JA EVM}$  is junction to ambient thermal resistance, which is tested on SCT EVM.

# **ELECTRICAL CHARACTERISTICS**

V<sub>IN</sub>=V<sub>OUT</sub>+1V, C<sub>OUT</sub>=10uF, T<sub>J</sub>= -40°C~125°C, typical value is tested under 25°C.

SYMBOL	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
Power Supp	ply					
V <sub>IN</sub>	Operating input voltage		1.7		6	V
	V <sub>IN</sub> UVLO Threshold	V <sub>IN</sub> rising		1.5	1.695	V
V <sub>UVLO</sub>	Hysteresis			100		mV
V <sub>IN</sub>	Operating input voltage	(SCT71005A01)	2.2		6	V
V/	V <sub>IN</sub> UVLO Threshold	V <sub>IN</sub> rising(SCT71005A01)		2	2.195	V
V <sub>UVLO</sub>	Hysteresis			100		mV
		EN=0, 2.2V≤V <sub>IN</sub> ≤2.8V, T <sub>J</sub> = 25°C		0.02	0.2	μA
I <sub>SHDN</sub>	Shutdown current from VIN pin	EN=0, 2.2V≤V <sub>IN</sub> ≤2.8V, T <sub>J</sub> = -40°C~125°C			1.2	μA
		EN float, no load, V <sub>IN</sub> =V <sub>OUT</sub> +1V, T <sub>J</sub> = 25°C		8	12	μA
lα	Quiescent current from GND pin	EN float, no load, V <sub>IN</sub> =V <sub>OUT</sub> +1V, T <sub>J</sub> = -40°C~125°C			16	μA
Regulated 0	Output Voltage and Current					
.,		lout=1mA , T <sub>J</sub> = 25°C	-1%		1%	
Vout	Output voltage accuracy	lout=1mA , T <sub>J</sub> = -40°C~125°C	-2%		2%	
	Feedback voltage accuracy	T <sub>J</sub> = 25°C(SCT71005A01)	693	700	703	mV
		T <sub>J</sub> = -40°C~125°C(SCT71005A01)	686	700	714	mV
$V_{REF}$		T <sub>J</sub> = 25°C(SCT71005A02)	495	500	505	mV
		T <sub>J</sub> = -40°C~125°C(SCT71005A02)	490	500	510	mV
	Line regulation	V <sub>IN</sub> =V <sub>OUT</sub> +1V to 6V, lout=1mA		7	25	mV
		V <sub>IN</sub> =V <sub>OUT</sub> +1V to 6V, Iout=1mA(Fixed Output-F33)		10	30	mV
		lout=1mA to 500mA(Adjustable Output)		10	20	mV
$\Delta V$ оит	Load regulation	lout=1mA to 500mA(Fixed Output-F12)		16	30	mV
	Load regulation	lout=1mA to 500mA(Fixed Output-F18)		16	40	mV
		lout=1mA to 500mA(Fixed Output- F33)		25	50	mV
	D	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =100mA		28		mV
	Dropout voltage <sup>(1)</sup> (Adjustable Output)	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =200mA		54		mV
	- 1 /	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =500mA		143		mV
	Descriptively and /5th of Octor	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =100mA		49		mV
$V_{\text{DROP}}$	Dropout voltage(Fixed Output- F18)	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =200mA		100		mV
	, 	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =500mA		297		mV
	Draw and walks as (First d. Onto.)	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =100mA		26		mV
	Dropout voltage(Fixed Output-F33)	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =200mA		54		mV
	,	V <sub>IN</sub> =V <sub>OUT</sub> -0.1V ,lout =500mA		138		mV
l <sub>OUT</sub>	Output current	V <sub>OUT</sub> in regulation	0		500	mA
loc	Output current limit	Vout short to 90% × Vout, T <sub>J</sub> = 25°C	600	800	1000	mA



SYMBOL	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT
		Vout short to 90% × Vout, T <sub>J</sub> = - 40°C~125°C	540		1100	mA
		V <sub>OUT</sub> short to 90% × V <sub>OUT</sub> , T <sub>J</sub> = 25°C(SCT71005FxxDXAR)	580	800	1100	mA
		V <sub>OUT</sub> short to 90% × V <sub>OUT</sub> , T <sub>J</sub> = - 40°C~125°C (SCT71005FxxDXAR)	520		1200	mA
Isc	Short current limit	V <sub>OUT</sub> =0V		290		mA
		V <sub>OUT</sub> =1.2V,I <sub>OUT</sub> =10mA, f=1kHz, C <sub>OUT</sub> =10µF		47		dB
PSRR	Power supply rejection ratio <sup>(2)</sup>	V <sub>OUT</sub> =1.2V,I <sub>OUT</sub> =10mA, f=10kHz, C <sub>OUT</sub> =10µF		31		dB
	over Voltage Protection	V <sub>OUT</sub> =1.2V,I <sub>OUT</sub> =10mA, f=100kHz, C <sub>OUT</sub> =10µF		44		dB
Over Voltag						
ОVРн	overshoot of Vout when discharge occur	V <sub>IN</sub> =3.3V		115%		
OVPL	overshoot of Vout when discharge disappear	V <sub>IN</sub> =3.3V		110%		
OVP <sub>Hys</sub>	overshoot of Vout hysteresis			5%		
Enable and	Soft-startup					
		V <sub>EN_H_1.8</sub> (V <sub>IN</sub> =1.8V)		0.63	0.9	V
$V_{\text{EN\_H}}$	Enable rising threshold	V <sub>EN_H_3.3</sub> (V <sub>IN</sub> =3.3V)		0.75	0.95	V
		V <sub>EN_H_5</sub> (V <sub>IN</sub> =5V)		0.867	1	V
		V <sub>EN_L_1.8</sub> (V <sub>IN</sub> =1.8V)	0.35	0.607		V
$V_{\text{EN\_L}}$	Enable falling threshold	V <sub>EN_L_3.3</sub> (V <sub>IN</sub> =3.3V)	0.45	0.66		V
		V <sub>EN_L_5</sub> (V <sub>IN</sub> =5V)	0.5	0.685		V
		V <sub>EN_Hys_1.8</sub> (V <sub>IN</sub> =1.8V)		23		mV
$V_{\text{EN\_Hys}}$	Enable threshold hysteresis	V <sub>EN_Hys_3.3</sub> (V <sub>IN</sub> =3.3V)		85		mV
		V <sub>EN_Hys_5</sub> (V <sub>IN</sub> =5V)		180		mV
I <sub>EN_0V</sub>	Enable pin current	EN=0			0.2	μΑ
I <sub>EN_3.3V</sub>	Enable pin current	EN=3.3V		0.01	0.2	μΑ
$R_{EN\_pulldown}$	enable pulldown resistor			648		kΩ
Tss	Soft-start time	V <sub>REF</sub> =700mV		2.05		ms
	Soft start times	V <sub>REF</sub> =500mV & Fixed Output		1.4		ms
Power Good	d	1	ı			1
V <sub>PG_R</sub>	PG rising threshold percentage	Vout/Vout(NOM), when Vout rising		90%		
V <sub>PG_F</sub>	PG falling threshold percentage	Vout/Vout(NOM), when Vout falling		80%		
V <sub>PG_LOW</sub>	PG output low voltage	PG sink 0.5mA		82		mV
R <sub>PG</sub>	PG pull down resistor	R <sub>PG</sub> =V <sub>PG_LOW</sub> /0.5mA		165		Ω
I <sub>PG_LKG</sub>	PG leakage current	PG=5V, V <sub>OUT</sub> in regulation			0.2	uA
Td_ <sub>PGR</sub>	PG signal turn to high delay	From Vout>0.90xVout(NOM) to PG rising edge delay time		170		us
Td_ <sub>PGF</sub>	PG signal turn to low delay	From Vout<0.80xVout(NOM) to PG falling edge delay time		88		us

**Active Discharge** 



SYMBOL	PARAMETER	TEST CONDITION	MIN	TYP	MAX	UNIT	
Rdischarge	Low output NMOS on resistance	EN=0,V <sub>IN</sub> =3.3V		133		Ω	
Thermal Pro	Thermal Protection						
T <sub>SD</sub>	Thermal shutdown threshold <sup>(3)</sup>	T <sub>J</sub> rising		170		°C	
150		Hysteresis		15		°C	

<sup>(1)</sup> The dropout voltage is defined as  $V_{IN}$ - $V_{OUT}$ , when force  $V_{IN}$  is 100mV below the value of  $V_{OUT}$  for  $V_{IN}$ = $V_{OUT(NOM)}$ +1V.



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<sup>(2)</sup> PSRR is derived from bench characterization, not production test.

<sup>(3)</sup> Thermal shutdown threshold is derived from bench characterization, not production test.

# TYPICAL CHARACTERISTICS

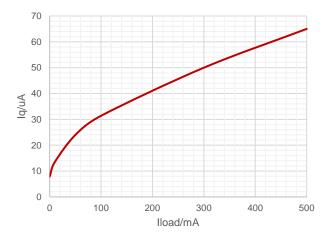


Figure 1. Quiescent Current vs Output Current

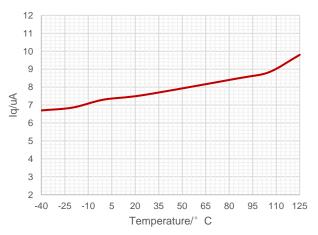


Figure 3. Quiescent Current vs Ambient Temperature

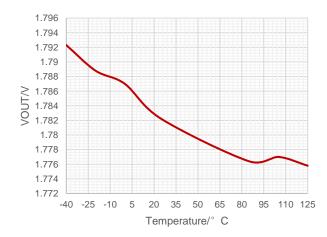


Figure 5. Output Voltage vs Ambient Temperature at VOUT=1.8V

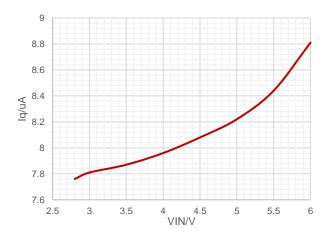


Figure 2. Quiescent Current vs Input Voltage, No load

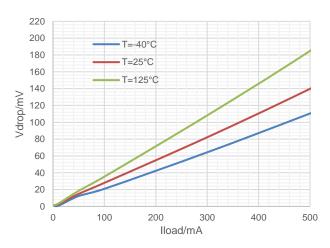


Figure 4. Dropout Voltage vs Output Current (Adjustable Output Version)

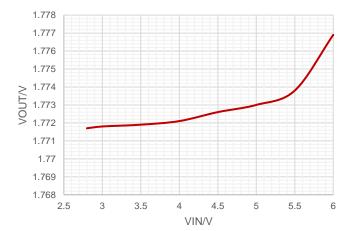


Figure 6. Output Voltage vs Input Voltage



# **TYPICAL CHARACTERISTICS (continued)**

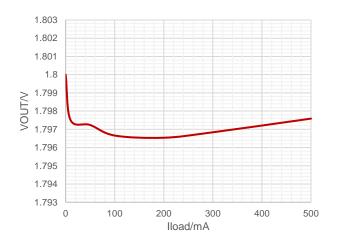


Figure 7. Output Voltage vs Output Current

(Adjustable Output Version)

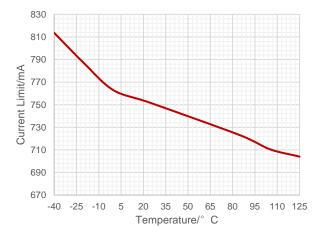


Figure 9. Output Current Limit vs Ambient Temperature

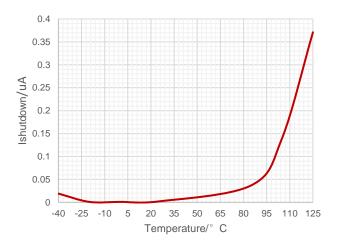


Figure 8. Shutdown Current vs Ambient Temperature

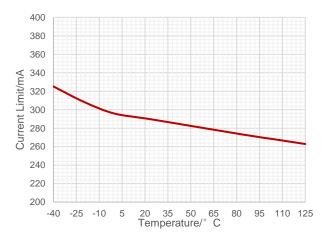


Figure 10. Short Current Limit vs Ambient Temperature



# **TYPICAL CHARACTERISTICS (continued)**

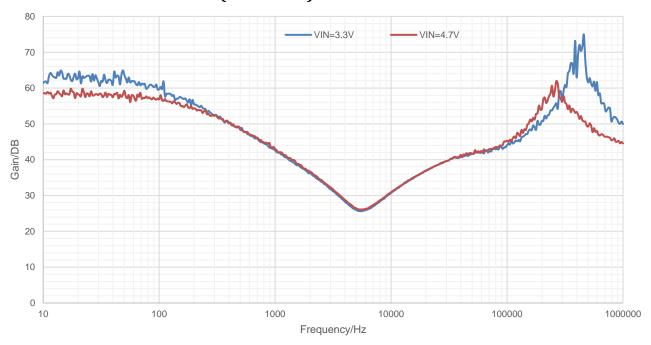


Figure 11. PSRR vs Frequency VOUT=1.2V,Cf=33pF,COUT=10uF,IOUT=10mA

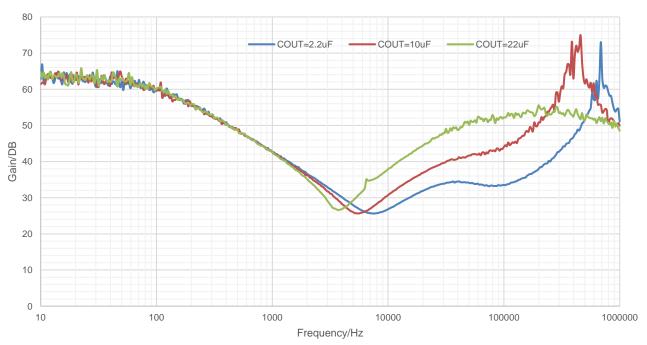


Figure 12. PSRR vs Frequency VIN=3.3V,VOUT=1.2V,Cf=33pF,IOUT=10mA



# **TYPICAL CHARACTERISTICS (continued)**

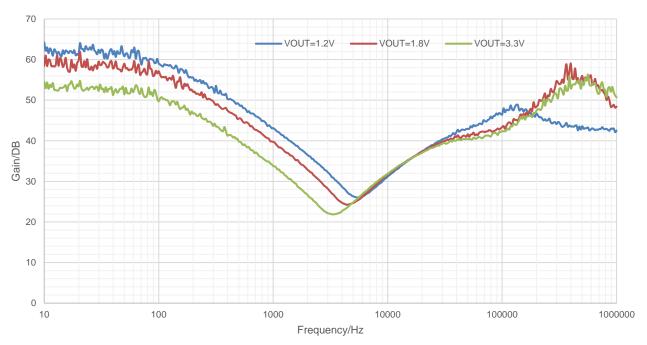


Figure 13. PSRR vs Frequency VIN=4.3V, Cf=33pF,COUT=10uF,IOUT=10mA

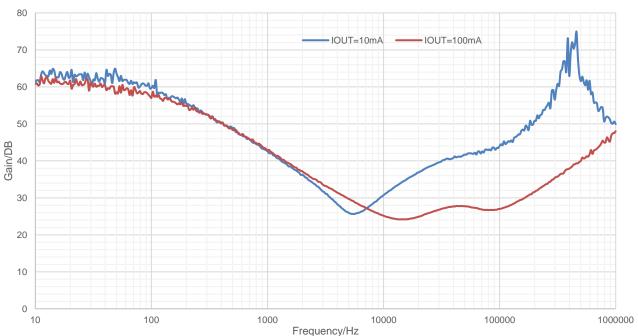


Figure 14. PSRR vs Frequency VIN=3.3V,VOUT=1.2V,Cf=33pF,COUT=10uF



# **FUNCTIONAL BLOCK DIAGRAM**

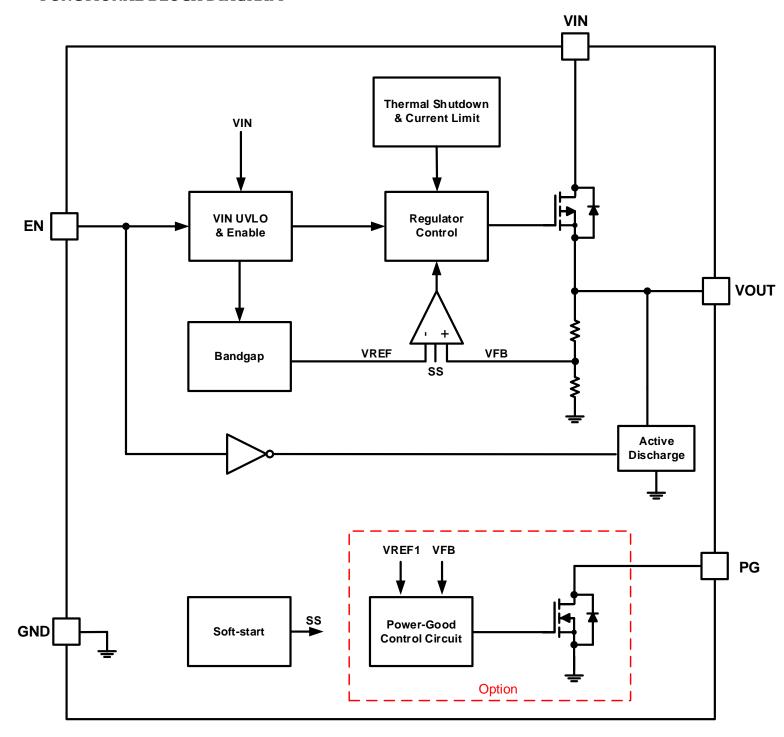


Figure 15. Functional Block Diagram of Fixed Output Version



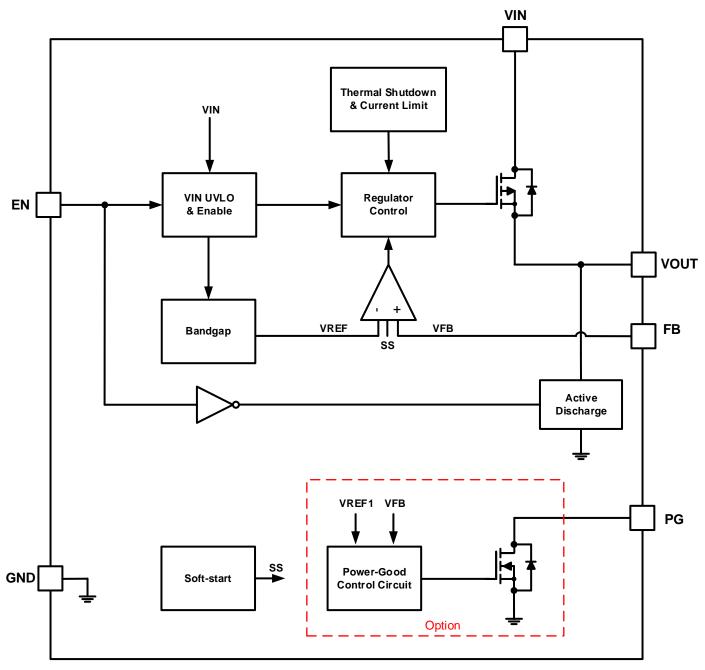


Figure 16. Functional Block Diagram of Adjust Output Version



### **OPERATION**

#### Overview

The SCT71005 product are 500mA output current linear regulators with very low quiescent current. These voltage regulators operate from 1.7V to 6V DC input voltage and consume 8µA quiescent current at no load.

The SCT71005 products are stable with 2.2uF~220uF output capacitors, and 10uF ceramic capacitor is recommended. An internal soft-start time avoids large inrush current and output voltage overshoot during startup.

The SCT71005 products also provide enable control which is very suitable for the applications needing sequence configuration. Other protection features include the VIN input under-voltage lockout, over current protection, output hard short protection with OCFB and thermal shutdown protection.

The SCT71005 series products are available in fixed voltage versions of 1.2V, 1.8V and 3.3V with 1% output voltage accuracy at room temp and 2% output voltage accuracy over operating conditions.

The SCT71005 series products also provide adjustable output version which can adjust the output voltage from 0.5V to 5V. The product is available in SOT23-5, TDFN2x2-6, DFN1x1-4 and TDFN2x3-8 packages.

If you need a new output voltage version or a new package option, please feel free to contact SCT sales.

### **Output Enable**

The enable pin (EN) is active high. Enable the device by forcing the voltage of the enable pin to exceed the minimum EN pin high-level input voltage. Turn off the device by forcing the voltage of the enable pin to drop below the maximum EN pin low-level input voltage. If shutdown capability is not required, connect EN to IN.

This EN circuit has an pulldown resistor(R<sub>EN\_pulldown</sub>) disconnected to reduce input current when the output is enabled, and connected when EN pin low to disable the output. Floating the EN pin is not suggestion.

### **Regulated Output Voltage**

The SCT71005 product provide adjustable output which can adjust the output voltage from 0.5V to 5V. When the input voltage is higher than  $V_{\text{OUT(NOM)}}+V_{\text{DROP}}$ , output pin is the regulated output based on the selected voltage version. When the input voltage falls below  $V_{\text{OUT(NOM)}}+V_{\text{DROP}}$ , output pin tracks the input voltage minus the dropout voltage based on the load current. When the input voltage drops below UVLO threshold, the output keeps shut off.

If you need a new output voltage version or a new package option, please feel free to contact SCT sales.

#### **Output Discharge**

The SCT71005 product has an internal pulldown MOSFET that connects an R<sub>discharge</sub> resistor to ground when the device is disabled to actively discharge the output voltage. The active discharge circuit is activated by the enable pin.

Do not rely on the active discharge circuit to discharge the output voltage after the input supply has collapsed because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device, especially when a large output capacitor is used. Limit reverse current to no more than 5% of the device rated current for a short period of time.

### **Over Current Limit and Foldback Current Limit**

The SCT71005 product has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brick-wall foldback scheme. The current limit transitions from a brick-wall scheme to a foldback scheme at the foldback voltage (V<sub>FOLDBACK</sub>). In a high-load current fault with the output voltage above V<sub>FOLDBACK</sub>, the brick-wall scheme limits the output current to the current limit (I<sub>OC</sub>). When the output voltage drops below V<sub>FOLDBACK</sub>, a foldback current limit activates that scales back the current limit. When the output is shorted, the device supplies a typical current called the short-circuit current limit (I<sub>SC</sub>). I<sub>OC</sub> and I<sub>SC</sub> are listed in the Electrical Characteristics table.



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The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the regulator begins to heat up because of the increase in power dissipation. When the device is in brick-wall current limit, the pass transistor dissipates power  $[(V_{IN}-V_{OUT})\times I_{OC}]$ . When the output is shorted and the output voltage is less than  $V_{FOLDBACK}$ , the pass transistor dissipates power  $[(V_{IN}-V_{OUT})\times I_{SC}]$ . If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition persists, the device cycles between current limit and thermal shutdown.

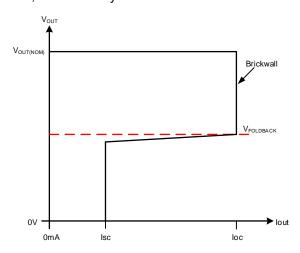


Figure 17. Current Limit with Foldback Feature

#### **Internal Soft-Start**

The SCT71005 product integrates an internal soft-start circuit that ramps the reference voltage from zero volts to 0.8V reference voltage in 1.4ms(SCT71005A02). If the EN pin is pulled below 0.607V, LDO will be shut off and the internal soft-start resets. The soft-start also resets during shutdown due to thermal overloading.

Below figure shows the startup waveform at small output capacitor and large output capacitor. When output capacitor is small, for example 10uF, the slope of VOUT is limit by soft-start. When output capacitor is large, for example 100uF, the slope of VOUT is limited by foldback current limit (Isc) at VOUT<VFOLDBACK, and the slope of VOUT is limited by over current limit (Ioc), when VOUT> VFOLDBACK.

In SCT71005 product, typical Tss is 1.4ms(SCT71005A02), and typical  $I_{OC}$  is 800mA and typical Isc is 290mA, could use the following formula for initial startup time calculation.

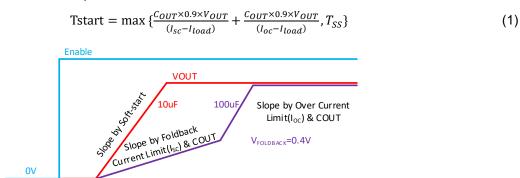


Figure 18. Soft-start Waveform vs Output Capacitor

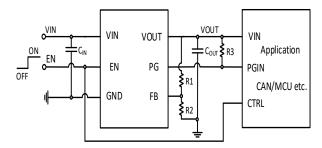


### **Power-Good and Power-Good Delay**

The power-good (PG) pin is an open-drain output and can be connected to any 5V or lower rail through an external pull-up resistor. The PG output is high-impedance when VOUT is greater than the PG trip threshold ( $V_{PG_R}=90\% \times V_{OUT(NOM)}$ ). If VOUT drops below  $V_{PG_F}=80\% \times V_{OUT(NOM)}$ , the open-drain output turns on and pulls the PG output low. If output voltage monitoring is not needed, the PG pin can be left floating or connected to GND.

The power-good delay time  $(Td_{PGR})$  is defined as the time period from when  $V_{OUT}$  exceeds the PG trip threshold voltage  $(V_{PG_R})$  to when the PG output is high. This power-good delay time is set by an internal time, which is 170us typical. The power-good deglitch time  $(Td_{PGF})$  is defined as the time period from when  $V_{OUT}$  fall below the PG trip threshold voltage  $(V_{PG_F})$  to when the PG output is low. This power-good deglitch time is set by an internal time, which is 88us typical. If the power-good delay time is not enough for some application, could try to connect a capacitor from PG pin to GND and using PG pull-up resistor and this capacitor generate extra delay time to meet your design.

To ensure proper operation of the power-good feature, maintain  $V_{IN} \ge 1.7V$  ( $V_{IN\_MIN}$ ). It allows connections of PG pin to circuit with the same or different power supply voltage to the LDO's VOUT level. Below are the connections examples.



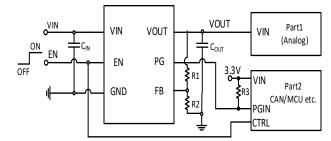


Figure 19. PG Connected to LDO's Ouput

Figure 20. PG Connected to the other Power Supply

Below figure shows the startup and shutdown situation when slow power up and power down.

At the point 0, the input voltage starts to rise from 0 to 5V, LDO is in shutdown (because VIN is below its UVLO threshold) and output voltage is 0V.

At the point 1, the VIN voltage reaches UVLO threshold level and LDO starts charging of output capacitor. VOUT rising speed is defined by internal soft-start function.

At the point 2, the VOUT voltage reaches almost the VIN voltage as it rises faster and LDO gets into dropout region. The difference between VIN and VOUT is the dropout voltage.

At the point 3, the VOUT reaches PG threshold (V<sub>PG\_R</sub>=90% x V<sub>OUT(NOM)</sub>) and from this point LDO counts the power good delay time (Td <sub>PGR</sub>). After this delay, the PG pin rises to high level showing that VOUT is ok.

At the point 4, the VOUT reaches its nominal value (3.3V) as the VIN starts to be higher than  $(V_{OUT(NOM)} + V_{DROP})$  and LDO gets into regulation region.

At the point 5, as the VIN voltage slow power down and LDO returns to dropout region again.

At the point 6, the VOUT drops below PG threshold (V<sub>PG\_F</sub>=80% x V<sub>OUT(NOM)</sub>) and LDO starts counting the power good deglitch time (Td\_PGF), which filters fast VOUT undershoots(caused for example by line/load transient responses). After this delay, the PG output is shorted to 0 V level to highlight "power fail" state.

At the point 7, the VIN voltage is lower than input voltage UVLO threshold minus UVLO hysteresis level and LDO goes into the shutdown state.



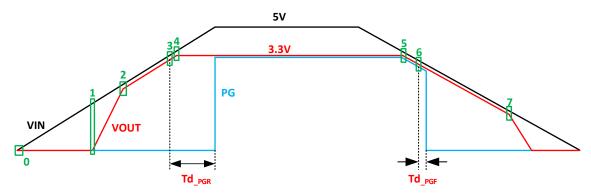


Figure 21. Startup and Shutdown Example —SCT71005 Series

### **Thermal Shutdown**

This device incorporates a thermal shutdown ( $T_{SD}$ ) circuit as a protection from overheating. For continuous normal operation, the junction temperature should not exceed the  $T_{SD}$  trip point. The junction temperature exceeding the  $T_{SD}$  trip point causes the output to turn off. When the junction temperature falls below the  $T_{SD}$  trip point minus thermal shutdown hysteresis, the output turns on again.



# APPLICATION INFORMATION

# Typical application 1:

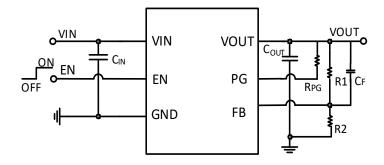


Figure 22. SCT71005 Typical Application Schematic

**Design Parameters** 

Design Parameters	Example Value
Input Voltage	5V Normal, 1.7V~6V
Output Voltage	0.5V~5V
Maximum Output Current	500mA
Output Capacitor Range (Cout)	2.2uF~22uF , recommends 10uF
Input Capacitor Range (C <sub>IN</sub> )	>2.2uF , recommends 10uF

# **Typical application 2:**

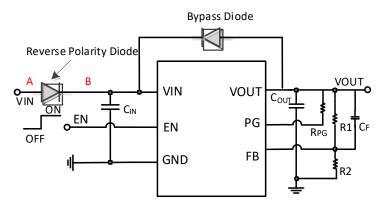


Figure 23. SCT71005 Typical Application Schematic with Reverse Polarity Diode

**Design Parameters** 

Design Parameters	Example Value
Input Voltage	5V Normal, 1.7V~6V
Output Voltage	0.5V~5V
Maximum Output Current	500mA
Output Capacitor Range (Cout)	2.2uF~22uF , recommends 10uF
Input Capacitor Range (C <sub>IN</sub> )	>2.2uF , recommends 10uF



In some applications, the VIN and the VOUT potential might be reversed, possibly resulting in circuit internal damage or damage to the elements. For example, the accumulated charge in the output pin capacitor flowing backward from the VOUT to the VIN when the VIN shorts to the GND. In order to minimize the damage in such case, use a capacitor with a capacitance less than 220µF. Also by inserting a reverse polarity diode in to the VIN, it can prevent reverse current from reverse battery connection or the case, when the point A is short-circuited GND. If there may be any possible case point B is short-circuited to GND, we also recommend using a bypass diode between the VIN and the VOUT.

### Typical application 3:

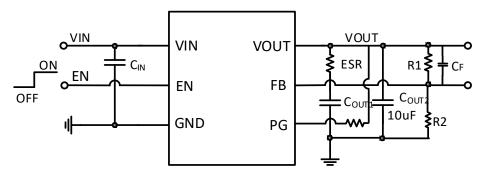


Figure 24. SCT71005 Typical Application Schematic with Large Output Capacitor

Design Parameters				
Design Parameters	Example Value			
Input Voltage	5V Normal, 1.7V~6V			
Output Voltage	0.5V~5V			
Maximum Output Current	500mA			
Output Capacitor Range (Coutland ESR)	2.2uF~220uF with ESR=0.5Ω~5Ω			
Output Capacitor Range (Cout2)	recommends 10uF with low ESR			
Input Capacitor Range (C <sub>IN</sub> )	>2.2uF , recommends 10uF			

### Typical application 4:

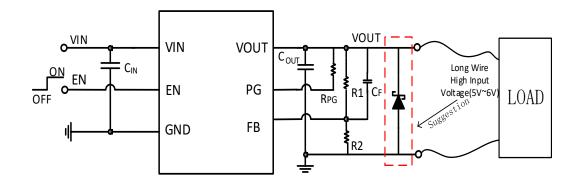


Figure 25. SCT71005 Typical Application Schematic with Long Wire and High Input Voltage



**Design Parameters** 

Design Parameters	Example Value
Input Voltage	5V Normal, 1.7V~6V
Output Voltage	0.5V~5V
Maximum Output Current	500mA
Output Capacitor Range (Coutland ESR)	2.2uF~220uF with ESR=0.5Ω~5Ω
Output Capacitor Range (Cout2)	recommends 10uF with low ESR
Input Capacitor Range (C <sub>IN</sub> )	>2.2uF , recommends 10uF

A Schottlky diode is suggested between VOUT and GND under the applications of hard short event at high input voltage when big distance exists between the device and loads.



## **Output Voltage**

The output voltage is set by an external resistor divider R1 and R2 in typical application schematic. Recommended R2 resistance is  $100k\Omega$ . Use equation 2 to calculate R1.

$$R_1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) * R_2 \tag{2}$$

where:

VREF is the feedback reference voltage, for SCT71005A01 is 700mV and SCT71005A02 is 500mV

Table 1: Compensation Values for Typical Output Voltage/Capacitor Combinations (SCT71005A01)

Vout/V	COUT/uF	Cf/pF	R1/kΩ	R2/kΩ	COUT1/uF (optional)	ESR/Ω
1.2	10	33	71.5	100	220	1
1.8	10	33	158	100	220	1
2.4	10	33	243	100	220	1
3.3	10	33	374	100	220	1
5	10	33	619	100	220	1

Table 2: Compensation Values for Typical Output Voltage/Capacitor Combinations (SCT71005A02)

Vout/V	COUT/uF	Cf/pF	R1/kΩ	R2/kΩ	COUT1/uF (optional)	ESR/Ω
1.2	10	33	140	100	220	1
1.8	10	33	261	100	220	1
2.4	10	33	383	100	220	1
3.3	10	33	562	100	220	1
5	10	33	909	100	220	1

### **Input Capacitor and Output Capacitor**

SCT recommends adding a  $2.2\mu F$  or greater capacitor with a  $0.1\mu F$  bypass capacitor in parallel at VIN pin to keep the input voltage stable. Aluminum electrolytic capacitor or other capacitor with high capacitance is suggested for the system power with large voltage spike. The voltage rating of the capacitors must be greater than the maximum input voltage

To ensure loop stability, the SCT71005 product requires an output capacitor with a minimum effective capacitance value of  $2.2\mu F$ . And the product could support output capacitor range from  $2.2\mu F$  to  $220\mu F$  and with an ESR range between  $0.001\Omega$  and  $5\Omega$ . SCT recommends selecting a X5R- or X7R-type  $4.7\mu F$ 10 $\mu F$ 10 ceramic capacitor with low ESR over temperature range to improve the load transient response.

To further improve loop stability, we recommend using feed forward capacitors. The specific values can refer to the Figure 26 and Figure 27.



When using large output capacitor with higher ESR resistor, for example 100 $\mu$ F output electrolytic capacitor with 10 ESR resistor in the application, SCT recommends adding extra 10 $\mu$ F low ESR output capacitor parallel connection with the large electrolytic capacitor, this will eliminate the undershoot/overshoot voltage caused by the large ESR resistor and get better load transient performance.

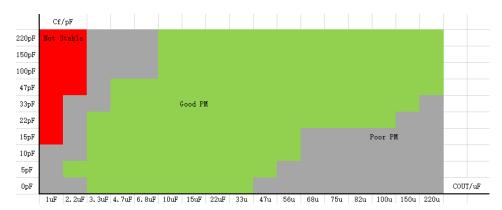


Figure 26. SCT71005 Feed Forward Capacitors recommend(R2=100kΩ,VOUT=1.8V)

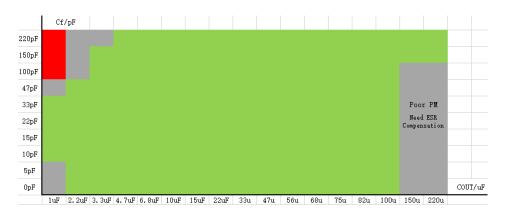


Figure 27. SCT71005 Feed Forward Capacitors recommend(R2=10kΩ,VOUT=1.8V)

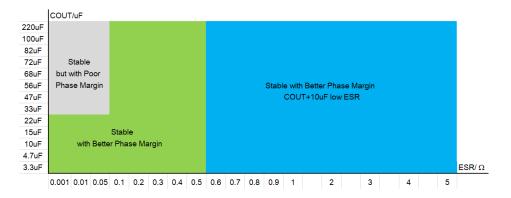


Figure 28. SCT71005 Stability vs Output Capacitor(Fixed Output)



### **Power Dissipation and Thermal Performance**

Power dissipation caused by voltage drop across the LDO and by the output current flowing through the device needs to be dissipated out from the chip. The maximum junction temperature is dependent on power dissipation, package, the PCB layout, number of used Cu layers, Cu layers thickness and the ambient temperature.

During normal operation, LDO junction temperature should not exceed 150°C, or else it may result in deterioration of the properties of the chip. Using below equations to calculate the power dissipation and estimate the junction temperature.

The power dissipation can be calculated using Equation 3. Because I<sub>GND</sub> « I<sub>OUT</sub>, the term V<sub>IN</sub> x I<sub>GND</sub> in Equation 3 could be ignored.

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$$
(3)

The junction temperature can be estimated using Equation 4. R<sub>0JA\_EVM</sub> is the junction-to-ambient thermal resistance based on customer's PCB. Verify the application and allow sufficient margins in the thermal design by the following method is used to calculate the junction temperature T<sub>J</sub>.

$$T_J = T_A + P_D \times R_{\theta JA\_EVM} \tag{4}$$

Reja\_evm is a critical parameter and depends on many factors such as the following:

- Power dissipation
- · Air temperature/flow
- PCB area
- Copper heat-sink area
- · Number of thermal vias under the package
- · Adjacent component placement

For the SCT71005 series products, the maximum allowable power dissipation of different packages was listed in the following table, and the test results are based on our EVM board, larger power dissipation will trigger thermal shutdown protection. As a result, we could calculate the R<sub>θJA\_EVM</sub> of different packages. The following table is just for your reference based on our EVM test, please leave enough margin when you design thermal performance.

The PCB information of our EVM: 4-layer,1oz Cu (inner 0.5oz Cu), 50mm x 30mm size.2-layer(only for DFN1X1-4), 1oz Cu, 50mm x 30mm size.

### Thermal Performance of Different Packages Based on EVM Test

Package	Max Allowable PD (W) (Not Trigger TSD,VOUT=1.8V)	Max Allowable PD (W) (TJ≤125℃)	R <sub>0JA_EVM</sub> (°C/W)
SOT23-5	1.579	1.089	91.81
TDFN2X2-6	2.033	1.402	71.31
TDFN2X3-8	2.46	1.694	59.04
DFN1X1-4 (2-layer)	1.032	0.711	140.55



# THERMAL CHARACTERISTICS

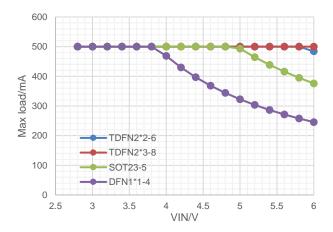


Figure 29. Maximum Output Current vs Input Voltage, VOUT=1.8V of Different Packages ,TJ ≤ TSD R

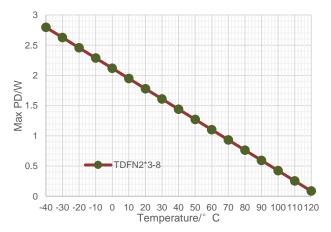


Figure 31. Maximum Allowed Power Dissipation vs Ambient Temperature, TDFN2x3-8,TJ ≤ 125 °C

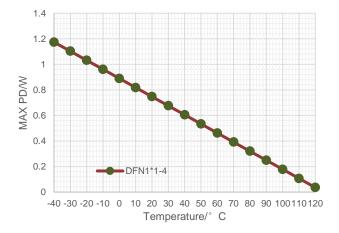


Figure 33. Maximum Allowed Power Dissipation vs Ambient Temperature, DFN1x1-4,TJ  $\leq$  125  $^{\circ}$ C

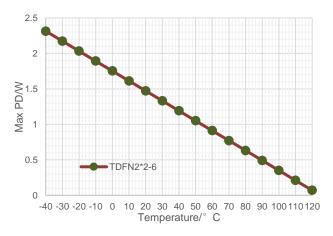


Figure 30. Maximum Allowed Power Dissipation vs Ambient Temperature, TDFN2x2-6,TJ  $\leq$  125  $^{\circ}$ C

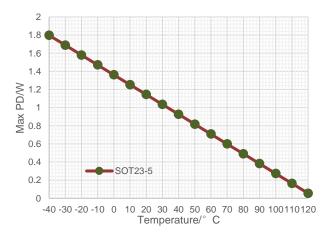


Figure 32. Maximum Allowed Power Dissipation vs Ambient Temperature, SOT23-5,TJ ≤ 125 °C



### **Application Waveforms**

Vin=Vout +1V, unless otherwise noted

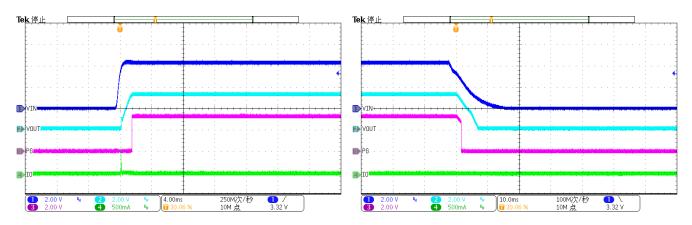


Figure 34. Power up (Iload=10mA)

Figure 35. Power down (Iload=10mA)

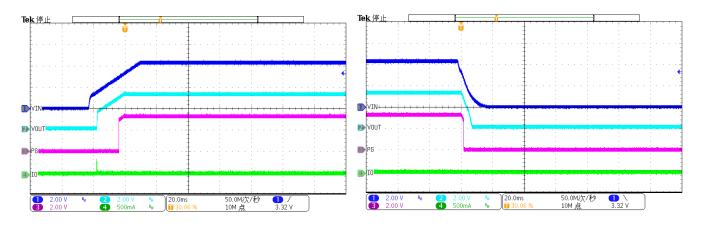


Figure 36. Slow Power up (Iload=10mA)

Figure 37. Slow Power down (Iload=10mA)

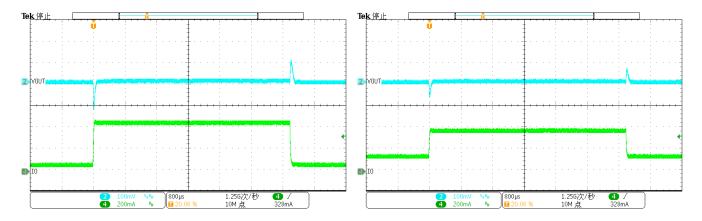


Figure 38. DC-DC Load Transient

(130mA-370mA), Vout=3.3V

(50mA-450mA), VOUT=3.3V



Figure 39. DC-DC Load Transient



# **Application Waveforms(Continued)**

Vin=Vout +1V, unless otherwise noted

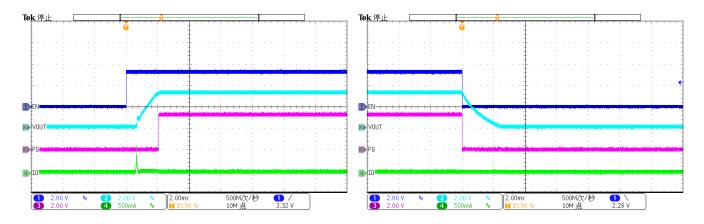


Figure 40. Enable (Iload=10mA)

Figure 41. Disable (Iload=10mA)

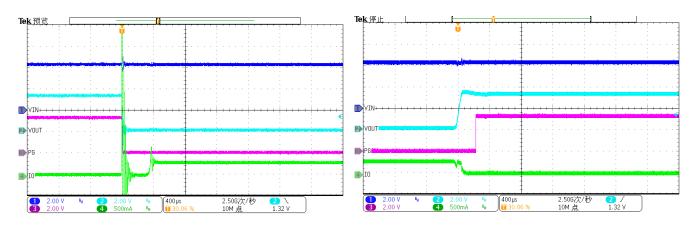


Figure 42. Enter Short Circuit Protection

Figure 43. Exit Short Circuit Protection

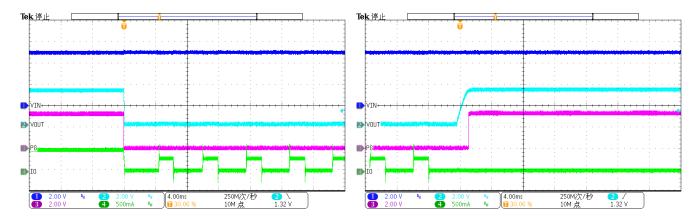


Figure 44. Enter Over Temperature Protection(Vin=5.5V)

Figure 45. Exit Over Temperature Protection(Vin=5.5V)



### **Layout Guideline**

Proper PCB layout is a critical for SCT71005's stability, transient performance and good regulation characteristics. For better results, follow these guidelines as below:

- 1. Both input capacitors and output capacitors must be placed as close to the device pins as possible.
- 2. It is recommended to bypass the input pin to ground with a  $0.1\mu\text{F}$  bypass capacitor. The loop area formed by the bypass capacitor connection,  $V_{\text{IN}}$  pin and the GND pin of the system must be as small as possible.
- 3. It is recommended to use wide trace lengths or thick copper weight to minimize I×R drop and heat dissipation.
- 4. To improve the thermal performance of the device, and maximize the current output at high ambient temperature, SCT recommends spreading the copper under the thermal pad as far as possible and placing enough thermal vias on the copper under the thermal pad.
- 5. If using large electrolytic capacitor with high ESR resistor, SCT recommends adding a 10uF low ESR capacitor parallel connection with the large electrolytic capacitor.

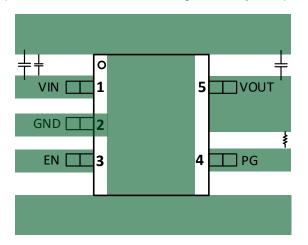


Figure 46. PCB Layout Example

#### SCT71005FxxTWDR

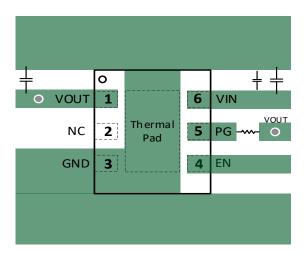


Figure 48. PCB Layout Example

SCT71005FxxDVAR

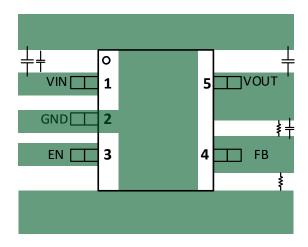


Figure 47. PCB Layout Example

### SCT71005A01TWDR

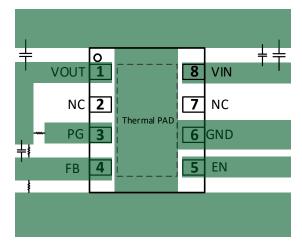


Figure 49. PCB Layout Example

SCT71005A02DTDR



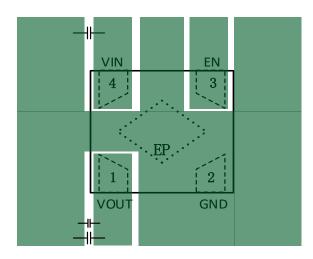
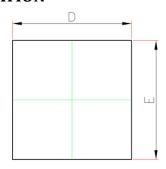


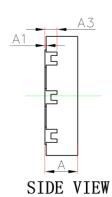
Figure 50. PCB Layout Example

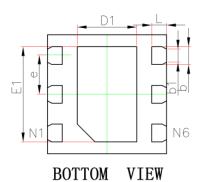
### SCT71005FxxDXAR





TOP VIEW



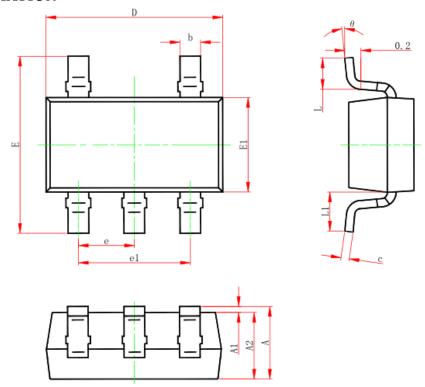


TDFN2x2-6 Package Outline Dimensions

Cymphol	Dimensions in Millimeters		Dimension	s in Inches
Symbol	Min.	Max.	Min.	Max.
Α	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.203	0.203 REF		REF.
D	1.900	2.100	0.075	0.083
E	1.900	2.100	0.075	0.083
D1	0.900	1.100	0.035	0.043
E1	1.500	1.700	0.059	0.067
b	0.250	0.350	0.010	0.014
b1	0.220 REF.		0.009 REF.	
е	0.650 BSC.		0.026	BSC.
L	0.174	0.326	0.007	0.013

- 1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
- 2. Drawing not to scale.
- 3. All linear dimensions are in millimeters.
- 4. Thermal pad shall be soldered on the board.
- 5. Dimensions of exposed pad on bottom of package do not include mold flash.
- 6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.



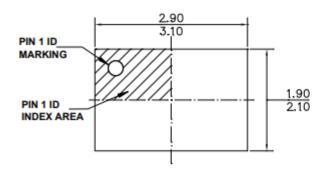


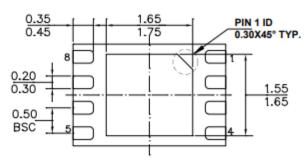
SOT23-5 Package Outline Dimensions

Cymphol	Dimensions	in Millimeters	Dimension	s in Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950	(BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
L1	0.600 REF		0.024	REF
θ	0°	8°	0°	8°

- 1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
- 2. Drawing not to scale.
- 3. All linear dimensions are in millimeters.
- 4. Thermal pad shall be soldered on the board.
- 5. Dimensions of exposed pad on bottom of package do not include mold flash.
- 6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.

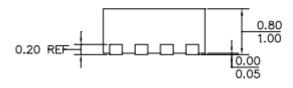




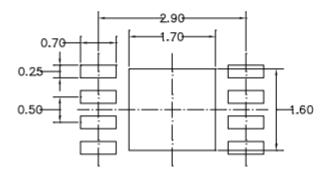


**TOP VIEW** 

**BOTTOM VIEW** 



### SIDE VIEW



#### NOTE:

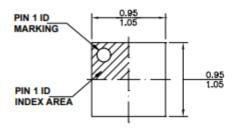
- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) LEAD COPLANARITY SHALL BE 0.08 MILLIMETERS MAX.
- 3) JEDEC REFERENCE IS MO-220.
- 4) DRAWING IS NOT TO SCALE.

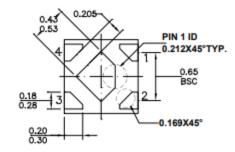
### RECOMMENDED LAND PATTERN

TDFN2x3-8 Package Outline Dimensions

- 1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
- 2. Drawing not to scale.
- 3. All linear dimensions are in millimeters.
- 4. Thermal pad shall be soldered on the board.
- 5. Dimensions of exposed pad on bottom of package do not include mold flash.
- 6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.

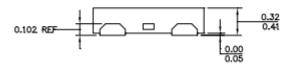




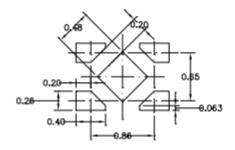


### **TOP VIEW**

**BOTTOM VIEW** 



### SIDE VIEW



#### NOTE:

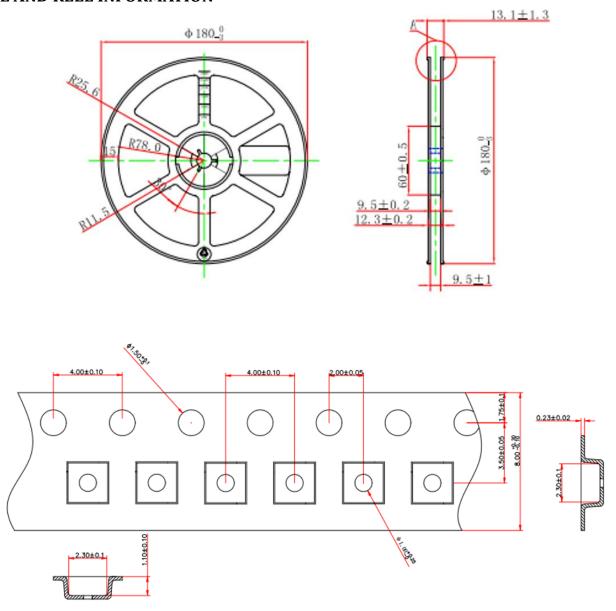
- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) LEAD COPLANARITY SHALL BE 0.08 MILLIMETERS MAX.
- 3) JEDEC REFERENCE IS MO-220.
- 4) DRAWING IS NOT TO SCALE.

RECOMMENDED LAND PATTERN

DFN1x1-4 Package Outline Dimensions

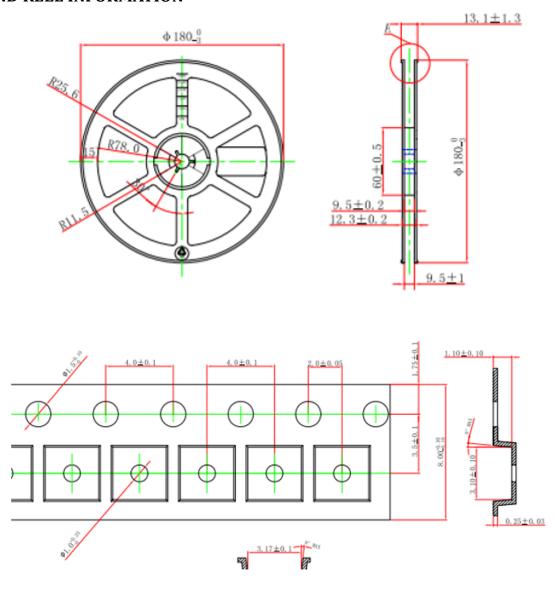
- 1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
- 2. Drawing not to scale.
- 3. All linear dimensions are in millimeters.
- 4. Thermal pad shall be soldered on the board.
- 5. Dimensions of exposed pad on bottom of package do not include mold flash.
- 6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.



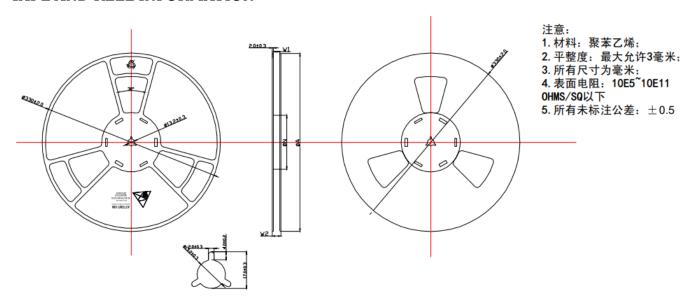


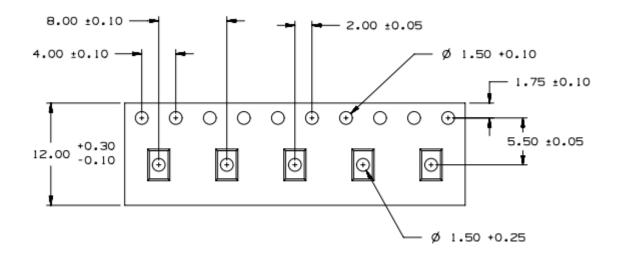
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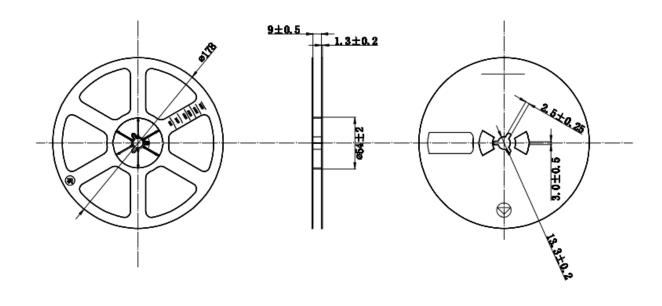
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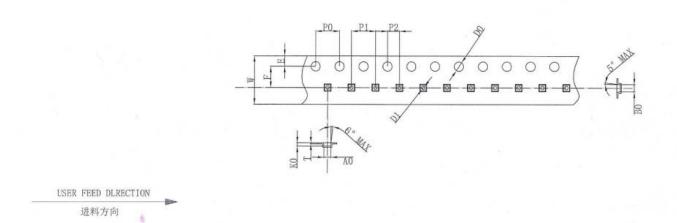




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